



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

2SD1620 — NPN Epitaxial Planar Silicon Transistor

1.5V, 3V Strobe Applications

Features

- Less power dissipation because of low $V_{CE(sat)}$, permitting more flashes of light to be emitted.
- Large current capacity and highly resistant to breakdown.
- Excellent linearity of h_{FE} in the region from low current to high current.
- Ultrasmall size supports high-density, ultrasmall-sized hybrid IC designs.

Specifications

Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		30	V
Collector-to-Emitter Voltage	V_{CEX}		20	V
Collector-to-Emitter Voltage	V_{CEO}		10	V
Emitter-to-Base Voltage	V_{EBO}		6	V
Collector Current	I_C		3	A
Collector Current (Pulse)	I_{CP}		5	A
Collector Dissipation	P_C		500	mW
		Mounted on a ceramic board (250mm \times 0.8mm)	1.3	W
Junction Temperature	T_j		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Electrical Characteristics at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=20\text{V}, I_E=0\text{A}$			100	nA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=4\text{V}, I_C=0\text{A}$			100	nA
DC Current Gain	h_{FE}	$V_{CE}=2\text{V}, I_C=3\text{A}$	140	210		
Gain-Bandwidth Product	f_T	$V_{CE}=10\text{V}, I_C=50\text{mA}$		200		MHz
Output Capacitance	C_{ob}	$V_{CB}=10\text{V}, f=1\text{MHz}$		30		pF

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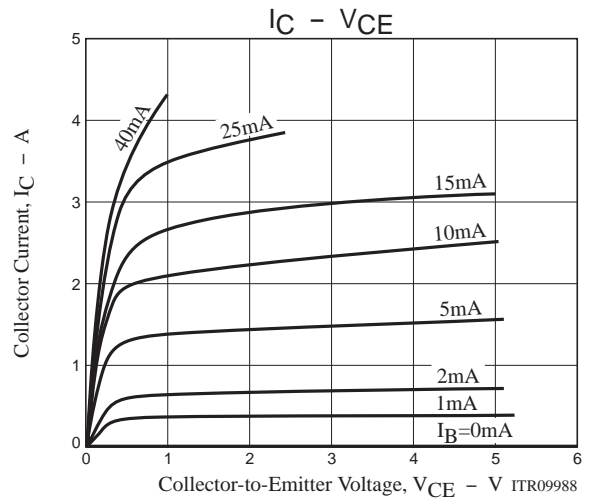
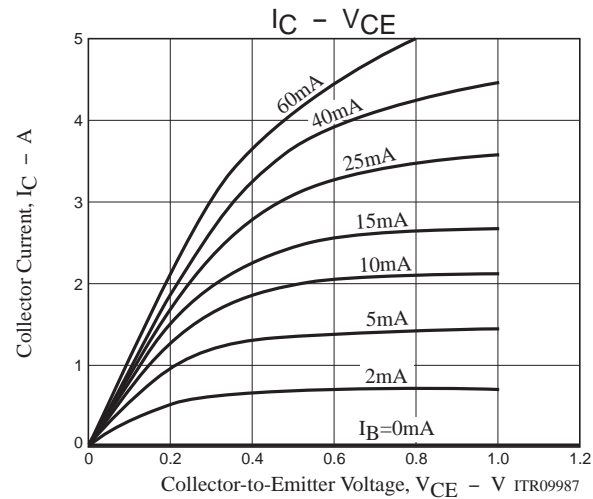
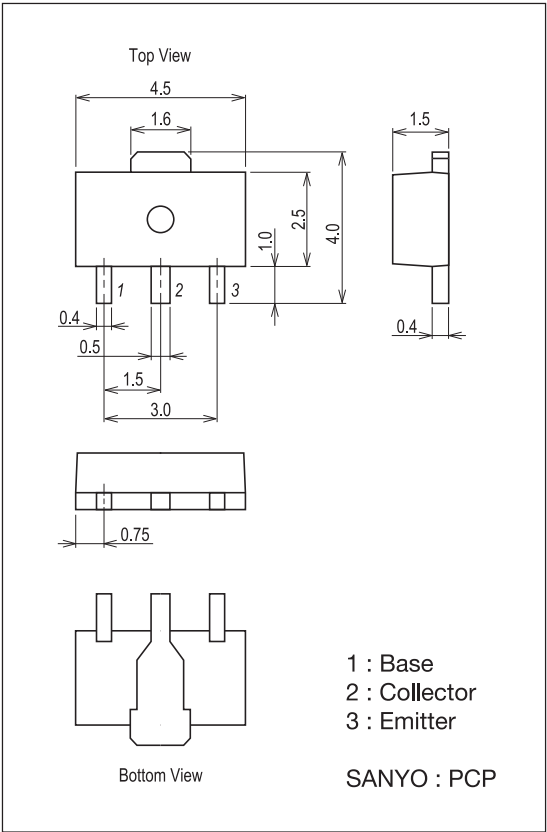
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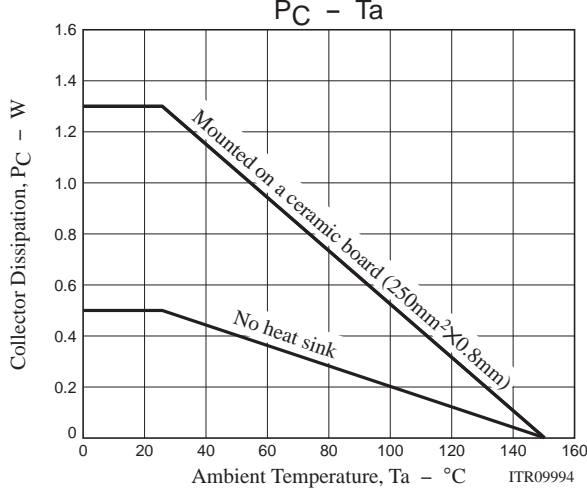
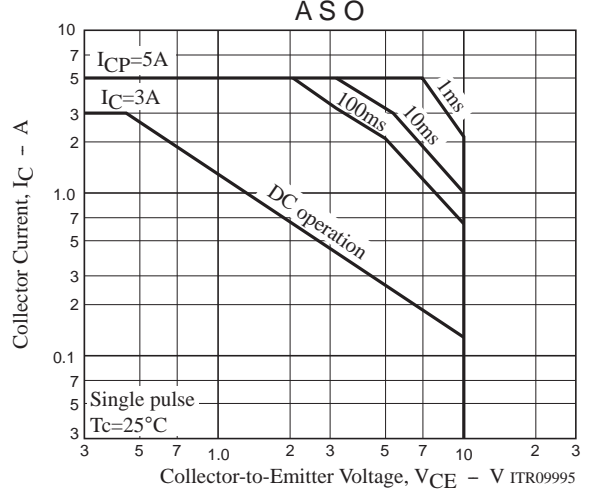
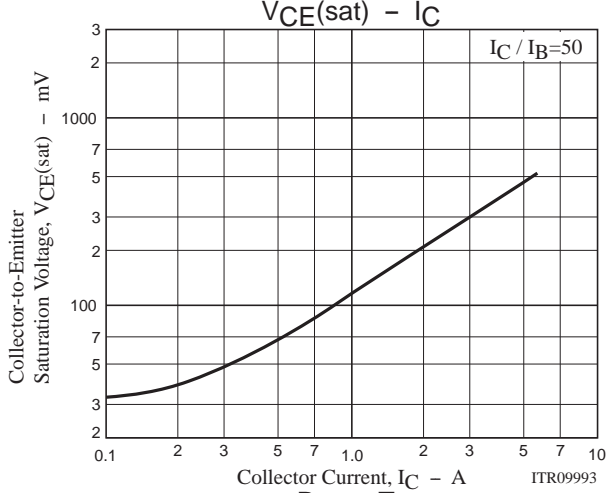
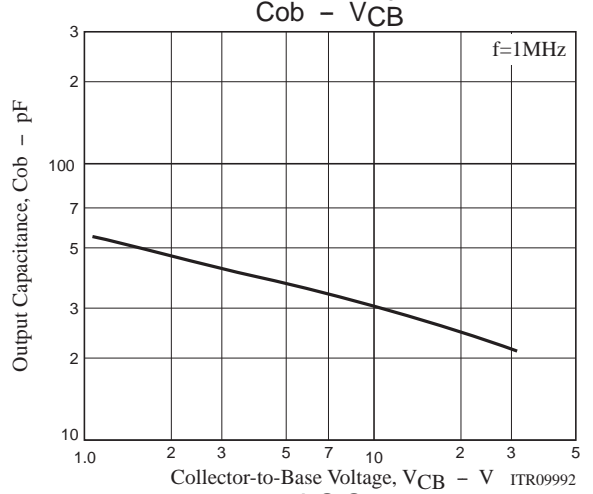
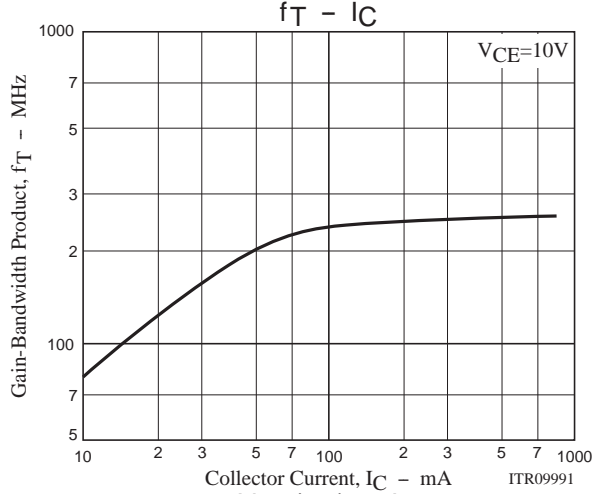
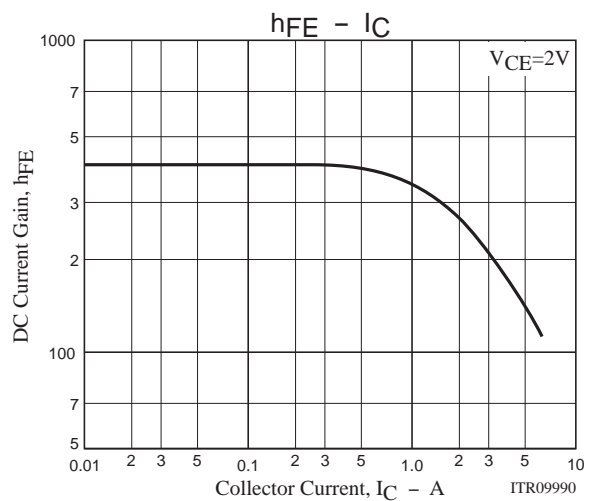
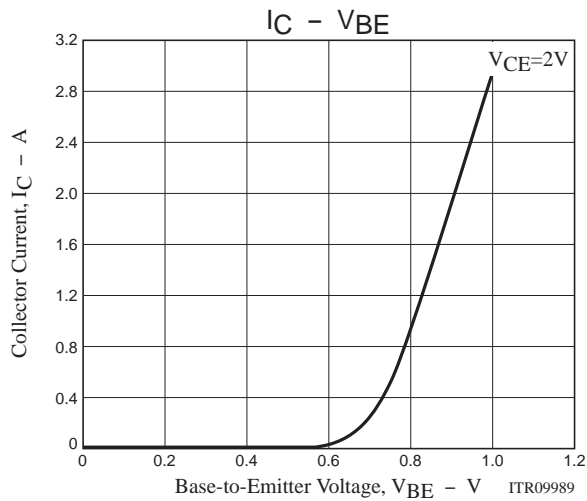
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=3A, I_B=60mA$		0.3	0.4	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=10\mu A, I_E=0A$	30			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEX}$	$I_C=1mA, V_{BE}=3V$	20			V
Collector-to-Emmitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=1mA, R_{BE}=\infty$	10			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=10\mu A, I_C=0A$	6			V

Package Dimensions

unit : mm (typ)
7007B-004





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